

View Online at <https://aerobasegroup.com/nsn/5961-01-535-2194>

Inclosure Material:

Plastic

Overall Length:

Between 0.180 inches and 0.200 inches

Terminal Length:

0.500 inches

Overall Diameter:

Between 0.145 inches and 0.165 inches

Mounting Method:

Terminal

Semiconductor Material:

Gallium arsenide

Voltage Rating In Volts Per Characteristic:

30.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter to collector, base open

Current Rating Per Characteristic:

0.55 microamperes service voltage

Maximum Operating Temperature Per Measurement Point:

100.0 degrees celsius ambient air

Product Name:

Infrared selected npn silicon phototransistor

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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